

ADD-A-PAK Generation VII Power Modules Thyristor/Diode and Thyristor/Thyristor, 95 A



ADD-A-PAK

FEATURES

- High voltage
- Industrial standard package
- UL pending
- 3500 V_{RMS} isolating voltage
- Low thermal resistance
- Totally lead (Pb)-free
- Designed and qualified for industrial level



RoHS
COMPLIANT

PRODUCT SUMMARY

| | |
|----------------------------|------|
| $I_{T(AV)}$ or $I_{F(AV)}$ | 95 A |
|----------------------------|------|

MECHANICAL DESCRIPTION

The ADD-A-PAK Generation VII, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- Up to 1600 V
- High surge capability
- Easy mounting on heatsink

ELECTRICAL DESCRIPTION

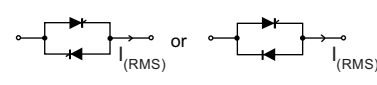
These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

MAJOR RATINGS AND CHARACTERISTICS

| SYMBOL | CHARACTERISTICS | VALUES | UNITS |
|----------------------------|-----------------|--------------|--------------------|
| $I_{T(AV)}$ or $I_{F(AV)}$ | 85 °C | 95 | A |
| $I_{O(RMS)}$ | As AC switch | 210 | |
| I_{TSM} , I_{FSM} | 50 Hz 60 Hz | 2000 2094 | |
| I^2t | 50 Hz | 20 | kA ² s |
| | 60 Hz | 18.26 | |
| $I^2\sqrt{t}$ | | 200 | kA ² √s |
| V_{RRM} | Range | 400 to 1600 | V |
| T_{Stg} | | - 40 to 125 | °C |
| T_J | | | |

ELECTRICAL SPECIFICATIONS

| VOLTAGE RATINGS | | | | | |
|-----------------|--------------|---|---|--|--|
| TYPE NUMBER | VOLTAGE CODE | V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | V _{DRM} , MAXIMUM REPETITIVE PEAK OFF-STATE VOLTAGE, GATE OPEN CIRCUIT V | I _{RRM} , I _{DRM} AT 125 °C mA |
| VSK.91 | 04 | 400 | 500 | 400 | 15 |
| | 06 | 600 | 700 | 600 | |
| | 08 | 800 | 900 | 800 | |
| | 10 | 1000 | 1100 | 1000 | |
| | 12 | 1200 | 1300 | 1200 | |
| | 14 | 1400 | 1500 | 1400 | |
| | 16 | 1600 | 1700 | 1600 | |

| ON-STATE CONDUCTION | | | | | | |
|--|--|--|---|---|--------------------|------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS | |
| Maximum average on-state current (thyristors) | I _{T(AV)} | 180° conduction, half sine wave, T _C = 85 °C | | 95 | A | |
| Maximum average forward current (diodes) | I _{F(AV)} | | | | | |
| Maximum continuous RMS on-state current, as AC switch | I _{O(RMS)} |  | | 210 | | |
| Maximum peak, one-cycle non-repetitive on-state or forward current | I _{TSM} or I _{FSM} | t = 10 ms | No voltage reapplied | Sinusoidal half wave, initial T _J = T _J maximum | | 2000 |
| | | t = 8.3 ms | | | | 2094 |
| | | t = 10 ms | 100 % V _{RRM} reapplied | | | 1682 |
| | | t = 8.3 ms | | | 1760 | |
| Maximum I ² t for fusing | I ² t | t = 10 ms | No voltage reapplied | Initial T _J = T _J maximum | 20 | |
| | | t = 8.3 ms | | | 18.26 | |
| | | t = 10 ms | 100 % V _{RRM} reapplied | | 14.14 | |
| | | t = 8.3 ms | | | 12.91 | |
| Maximum I ² √t for fusing | I ² √t (1) | t = 0.1 ms to 10 ms, no voltage reapplied T _J = T _J maximum | | 200 | kA ² √s | |
| Maximum value or threshold voltage | V _{T(TO)} (2) | Low level (3) | T _J = T _J maximum | 0.97 | V | |
| | | High level (4) | | 1.1 | | |
| Maximum value of on-state slope resistance | r _t (2) | Low level (3) | T _J = T _J maximum | 2.76 | mΩ | |
| | | High level (4) | | 2.38 | | |
| Maximum peak on-state or forward voltage | V _{TM} | I _{TM} = π × I _{T(AV)} | T _J = 25 °C | 1.73 | V | |
| | V _{FM} | I _{FM} = π × I _{F(AV)} | | | | |
| Maximum non-repetitive rate of rise of turned on current | di/dt | T _J = 25 °C, from 0.67 V _{DRM} , I _{TM} = π × I _{T(AV)} , I _g = 500 mA, t _r < 0.5 μs, t _p > 6 μs | | 150 | A/μs | |
| Maximum holding current | I _H | T _J = 25 °C, anode supply = 6 V, resistive load, gate open circuit | | 250 | mA | |
| Maximum latching current | I _L | T _J = 25 °C, anode supply = 6 V, resistive load | | 400 | | |

Notes

- (1) I²t for time t_x = I²√t × √t_x
- (2) Average power = V_{T(TO)} × I_{T(AV)} + r_t × (I_{T(RMS)})²
- (3) 16.7 % × π × I_{AV} < I < π × I_{AV}
- (4) I > π × I_{AV}



| TRIGGERING | | | | | |
|--|-------------|---|-----------------------------------|--------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS |
| Maximum peak gate power | P_{GM} | | | 12 | W |
| Maximum average gate power | $P_{G(AV)}$ | | | 3.0 | |
| Maximum peak gate current | I_{GM} | | | 3.0 | A |
| Maximum peak negative gate voltage | $-V_{GM}$ | | | 10 | V |
| Maximum gate voltage required to trigger | V_{GT} | $T_J = -40\text{ °C}$ | Anode supply = 6 V resistive load | 4.0 | |
| | | $T_J = 25\text{ °C}$ | | 2.5 | |
| | | $T_J = 125\text{ °C}$ | | 1.7 | |
| Maximum gate current required to trigger | I_{GT} | $T_J = -40\text{ °C}$ | Anode supply = 6 V resistive load | 270 | mA |
| | | $T_J = 25\text{ °C}$ | | 150 | |
| | | $T_J = 125\text{ °C}$ | | 80 | |
| Maximum gate voltage that will not trigger | V_{GD} | $T_J = 125\text{ °C}$, rated V_{DRM} applied | | 0.25 | V |
| Maximum gate current that will not trigger | I_{GD} | $T_J = 125\text{ °C}$, rated V_{DRM} applied | | 6 | mA |

| BLOCKING | | | | | |
|---|--------------------------|--|--|--------|------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS |
| Maximum peak reverse and off-state leakage current at V_{RRM} , V_{DRM} | I_{RRM} , I_{DRM} | $T_J = 125\text{ °C}$, gate open circuit | | 15 | mA |
| RMS insulation voltage | V_{INS} | 50 Hz, 1 s | | 3500 | V |
| Maximum critical rate of rise of off-state voltage | dV/dt | $T_J = 125\text{ °C}$, linear to $0.67 V_{DRM}$ | | 1000 | V/ μ s |

| THERMAL AND MECHANICAL SPECIFICATIONS | | | | | |
|---|-------------------|--|-------|---------------------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS |
| Junction operating and storage temperature range | T_J , T_{Stg} | | | - 40 to 125 | °C |
| Maximum internal thermal resistance, junction to case per leg | R_{thJC} | DC operation | | 0.22 | °C/W |
| Typical thermal resistance, case to heatsink per module | R_{thCS} | Mounting surface flat, smooth and greased | | 0.1 | |
| Mounting torque $\pm 10\%$ | to heatsink | A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound. | | 4 | Nm |
| | busbar | | | 3 | |
| Approximate weight | | | | 75 | g |
| | | | | 2.7 | oz. |
| Case style | | | JEDEC | TO-240AA compatible | |

| ΔR CONDUCTION PER JUNCTION | | | | | | | | | | | |
|------------------------------------|---------------------------|-------|-------|-------|-------|-----------------------------|-------|-------|-------|-------|-------|
| DEVICES | SINE HALF WAVE CONDUCTION | | | | | RECTANGULAR WAVE CONDUCTION | | | | | UNITS |
| | 180° | 120° | 90° | 60° | 30° | 180° | 120° | 90° | 60° | 30° | |
| VSK.91.. | 0.04 | 0.048 | 0.063 | 0.085 | 0.125 | 0.033 | 0.052 | 0.067 | 0.088 | 0.127 | °C/W |

Note

- Table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC



Fig. 1 - Current Ratings Characteristics



Fig. 4 - On-State Power Loss Characteristics

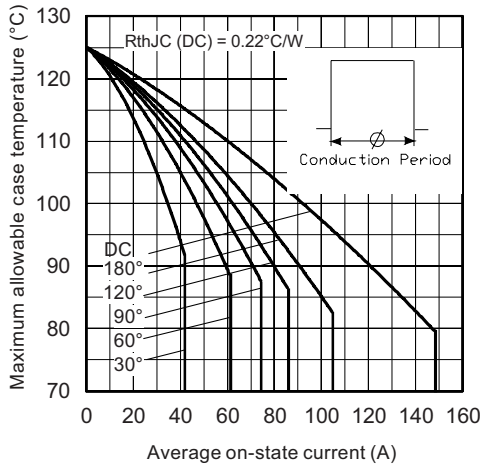


Fig. 2 - Current Ratings Characteristics



Fig. 5 - Maximum Non-Repetitive Surge Current

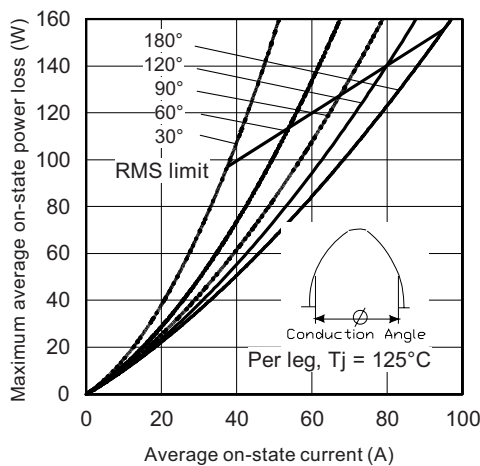


Fig. 3 - On-State Power Loss Characteristics



Fig. 6 - Maximum Non-Repetitive Surge Current

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Fig. 7 - On-State Power Loss Characteristics



Fig. 8 - On-State Power Loss Characteristics



Fig. 9 - On-State Power Loss Characteristics



Fig. 10 - On-State Voltage Drop Characteristics



Fig. 11 - Thermal Impedance Z_{thJC} Characteristics



Fig. 12 - Gate Characteristics



ORDERING INFORMATION TABLE



- 1 - Module type
- 2 - Circuit configuration (see end of datasheet)
- 3 - Current code (95 A)
- 4 - Voltage code (see Voltage Ratings table)

Note

- To order the optional hardware go to www.vishay.com/doc?95172

CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS

Dimensions

<http://www.vishay.com/doc?95368>



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